

MILITARY SPECIFICATION

SEMICONDUCTOR DEVICE, DIODE, SILICON, SWITCHING
TYPES 1N3064, 1N4454, 1N4454-1, AND 1N4532
JAN, JANTX, AND JANTXV

This amendment forms a part of MIL-S-19500/144G, dated 25 April 1984,
and is approved for use by all Departments and Agencies of the Depart-
ment of Defense.

PAGE 2

* 3.4, add the following:

"c. Lot identification code.

d. The "1N" portion of the type designation."

PAGE 4

4.3.1, power burn-in conditions table, middle column: Delete "f = 60 Hz" and
substitute "f = 60 Hz (see 4.5.2)".

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* Table IV, step 5, conditions column: Delete "V_R = 20 V dc" and substitute
"V_R = 50 V dc".

The margins of this amendment are marked with an asterisk to indicate where changes
(additions, modifications, corrections, deletions) from the previous amendment were
made. This was done as a convenience only and the Government assumes no liability
whatsoever for any inaccuracies in these notations. Bidders and contractors are
cautioned to evaluate the requirements of this document based on the entire content
irrespective of the marginal notations and relationship to the last previous
amendment.

Custodians:

Army - ER
Navy - EC
Air Force - 17

Preparing activity:
Navy - EC

Agent:
DLA - ES

Review activities:

Army - AR, MI
Navy - OS, SH
Air Force - 11, 95, 99
DLA - ES

(Project 5961-1014)

User activities:

Army - SM
Navy - AS, CG, MC
Air Force - 19